**Product data sheet** 

## 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Logic level compatible
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

## 3. Applications

- High-side load switch
- Battery management
- DC-to-DC conversion
- Switching circuits

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-30	V
V <sub>GS</sub>	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	-17.7	Α
Static characte	eristics			·			
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = -10 V; $I_D$ = -10.8 A; $T_j$ = 25 °C		-	7.7	9.1	mΩ
	resistance	$V_{GS}$ = -4.5 V; $I_D$ = -9.1 A; $T_j$ = 25 °C		-	10.2	12.8	mΩ

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



30 V, P-channel Trench MOSFET

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	D I
2	S	source		
3	S	source		G (F)
4	G	gate	Г П	s
5	D	drain		017aaa257
6	D	drain		
7	D	drain	MLPAK33 (SOT8002-1)	
8	D	drain		

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
PXP9R1-30QL		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1			

## 7. Marking

#### **Table 4. Marking codes**

Type number	Marking code
PXP9R1-30QL	9AY

30 V, P-channel Trench MOSFET

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-30	V
$V_{GS}$	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-17.7	Α
		V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C	[1]	-	-10.9	Α
		V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 100 °C	[1]	-	-6.8	Α
		V <sub>GS</sub> = -10 V; T <sub>sp</sub> = 25 °C		-	-57.2	Α
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-94.3	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	4.8	W
		T <sub>amb</sub> = 25 °C	[1]	-	1.8	W
		T <sub>sp</sub> = 25 °C		-	50	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode		'	1	,	,
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1.7	Α

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

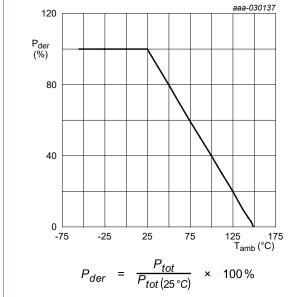


Fig. 1. Normalized total power dissipation as a function of ambient temperature

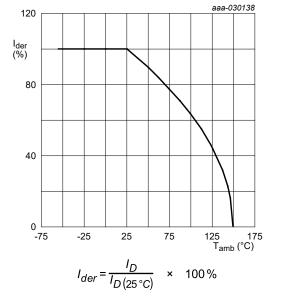


Fig. 2. Normalized continous drain current as a function of ambient temperature

### 30 V, P-channel Trench MOSFET

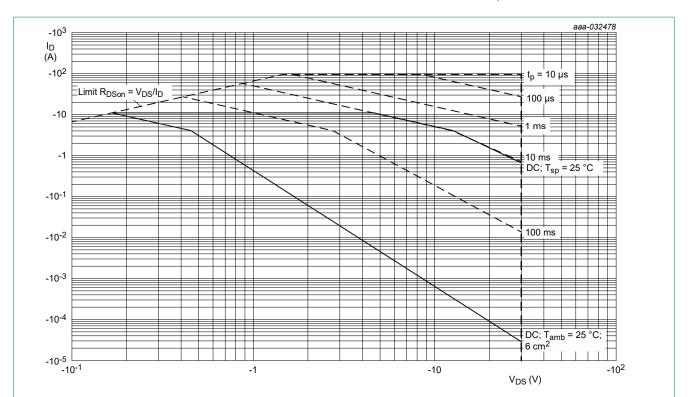


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

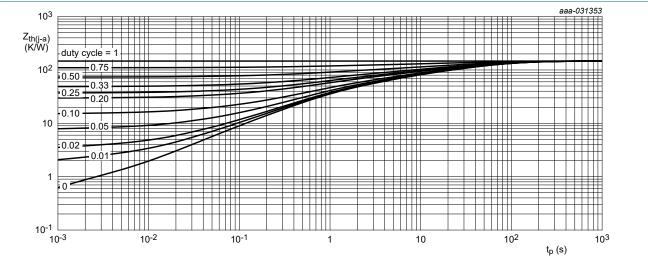
30 V, P-channel Trench MOSFET

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistance from	in free air	[1]	-	145	185	K/W
	junction to ambient	[2	[2]	-	55	70	K/W
		in free air; t ≤ 5 s	[2]	-	21	26	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	1.5	2.5	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

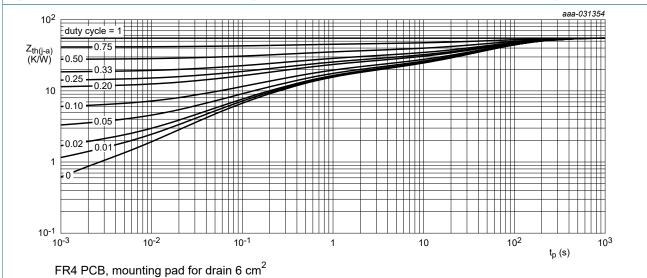


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

30 V, P-channel Trench MOSFET

## 10. Characteristics

#### **Table 7. Characteristics**

	V V V μΑ μΑ mΩ mΩ S
-1 -0.1 0.1 9.1 15.3 12.8 -	V μΑ μΑ μΑ mΩ mΩ S
-1 -0.1 0.1 9.1 15.3 12.8 -	μΑ μΑ μΑ mΩ mΩ S
-0.1 0.1 9.1 15.3 12.8 -	μΑ μΑ mΩ mΩ s
0.1 9.1 15.3 12.8 - -	μΑ mΩ mΩ mΩ S
9.1 15.3 12.8 - - -	mΩ mΩ mΩ S
15.3 12.8 86	mΩ mΩ S
12.8	mΩ S
- 86	S Ω
86	Ω
86	
	nC
	nC
43	
	nC
-	V
O -	pF
-	pF
-	pF
-	ns
'	
-1.2	V
-	ns
-	nC
-	ns
	ns

### 30 V, P-channel Trench MOSFET

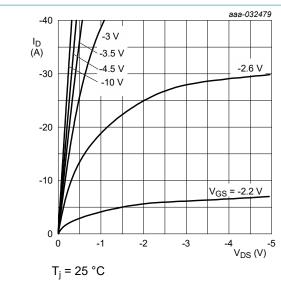


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

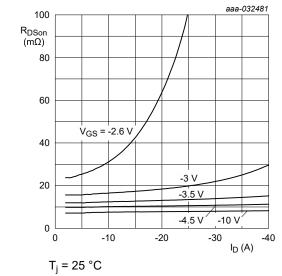


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

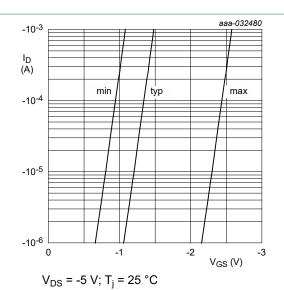


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

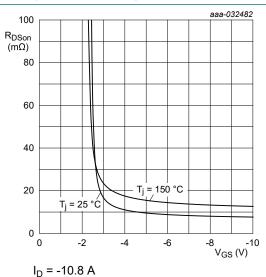


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

### 30 V, P-channel Trench MOSFET

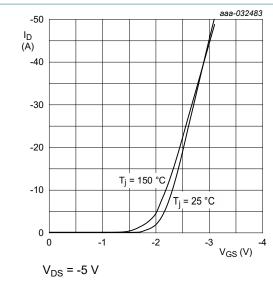


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

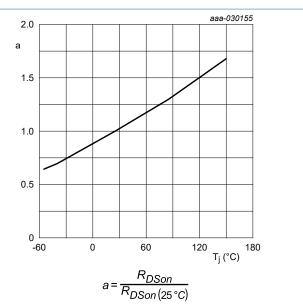


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

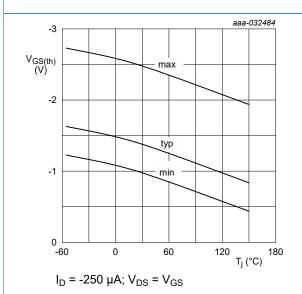
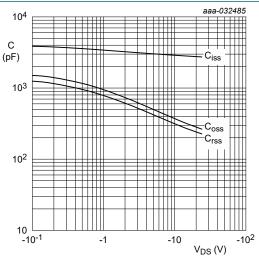


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$ 

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

#### 30 V, P-channel Trench MOSFET

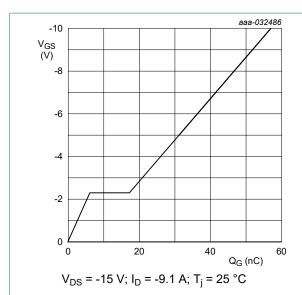


Fig. 14. Gate-source voltage as a function of gate charge; typical values

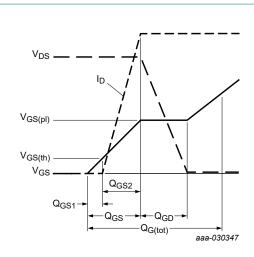


Fig. 15. Gate charge waveform definitions

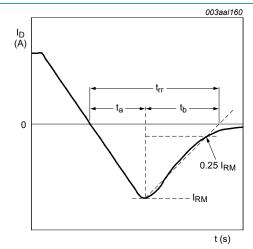


Fig. 16. Reverse recovery timing definition

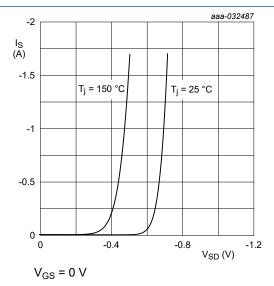
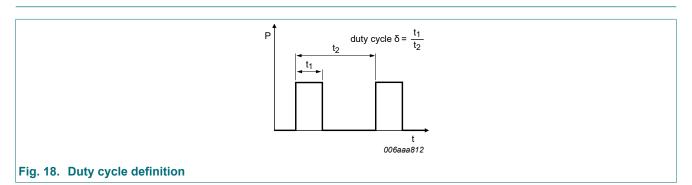


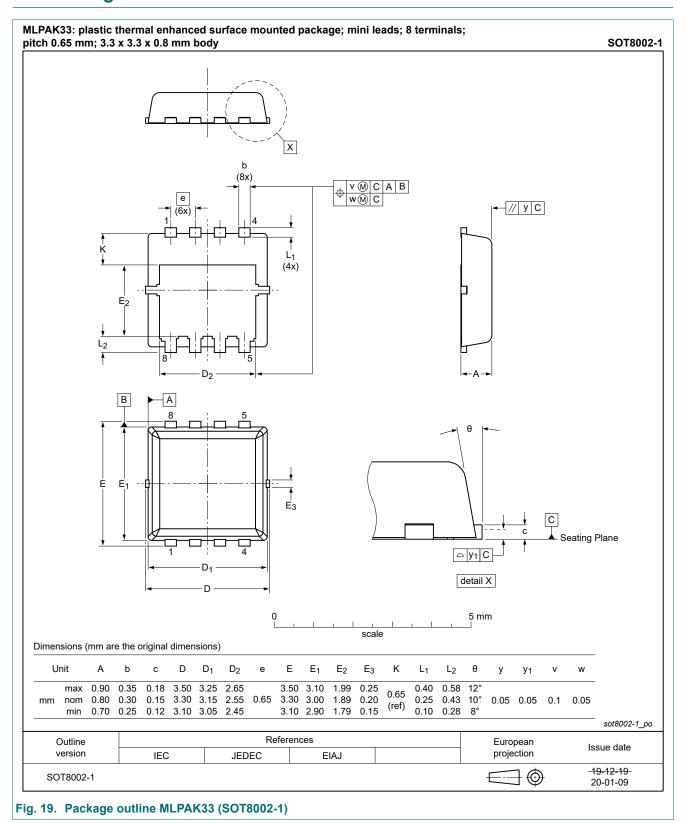
Fig. 17. Source current as a function of source-drain voltage; typical values

### 11. Test information



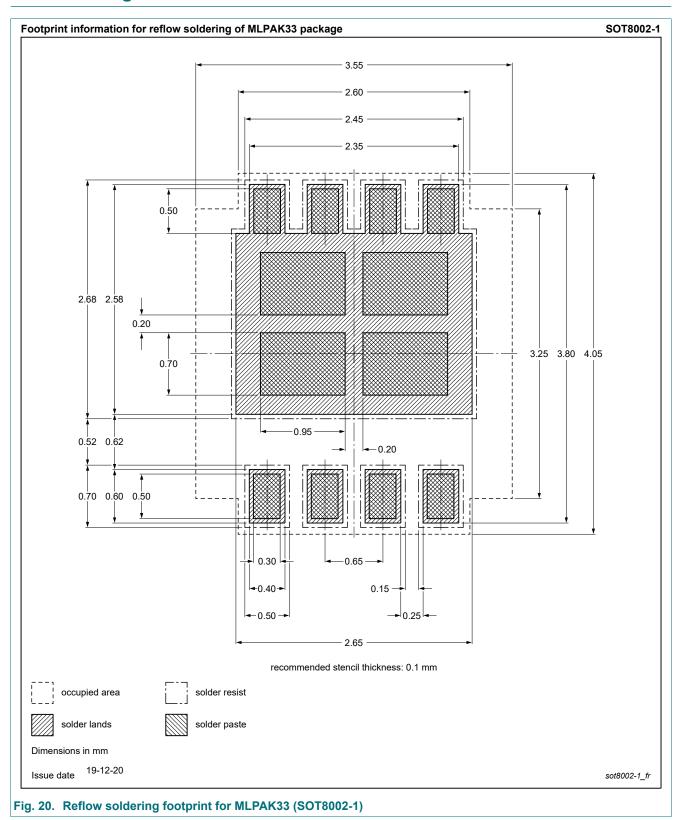
30 V, P-channel Trench MOSFET

## 12. Package outline



30 V, P-channel Trench MOSFET

## 13. Soldering



30 V, P-channel Trench MOSFET

# 14. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PXP9R1-30QL v.1	20210105	Product data sheet	-	-

#### 30 V, P-channel Trench MOSFET

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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### 30 V, P-channel Trench MOSFET

## **Contents**

General description	. 1
Features and benefits	1
Applications	1
Quick reference data	. 1
Pinning information	. 2
Ordering information	. 2
Marking	. 2
Limiting values	3
Thermal characteristics	5
Characteristics	. 6
Test information	. 9
Package outline1	10
Soldering 1	11
Revision history1	12
Legal information1	
	Features and benefits

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